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Coexistence of covalent and metallic bonding in the boron intercalation superconductor MgB_2

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Chemical bonding and electronic structure of MgB_2, a boron-based newly discovered superconductor, is studied using self-consistent band-structure techniques. Analysis of the transformation of the band structure for the hypothetical series of graphite–primitive graphite–primitive graphitelike boron–intercalated boron, shows that the band structure of MgB_2 is graphitelike, with π bands falling deeper than in ordinary graphite. These bands possess a typically delocalized and metallic, as opposed to covalent, character. The in-plane σ bands retain their two-dimensional (2D) covalent character, but exhibit a metallic hole-type conductivity. The coexistence of 2D covalent in-plane and three-dimensional (3D) metallic-type interlayer conducting bands is a peculiar feature of MgB_2. We analyze the 2D and 3D features of the band structure of MgB_2 and related compounds, and their contributions to conductivity.

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The recent discovery of superconductivity (SC) in MgB_2 (Ref. 1) has stimulated significant interest in this system.[2,3] One of the first questions is whether MgB_2 represents a new class of superconductors, or whether it is related to other known classes in terms of its bonding and electronic properties. The crystal structure of MgB_2 may be regarded as that of completely intercalated graphite[4] with carbon replaced by boron (its neighbor in the Periodic Table). In addition, MgB_2 is formally isoelectronic to graphite. Therefore, understanding the bonding and electronic properties of MgB_2 and its relation to graphite intercalation compounds (GIC's), some of which also exhibit SC, is desirable and is the subject of this paper.

The search for high-temperature superconductivity in carbon phases started in 1965 when $T_c = 0.55$ K in KC_8 was reported, and SC was subsequently explained in terms of the interaction of π-derived bands with the longitudinal phonon modes of the graphite layer.[5] Similar conclusions for the electronic structure at the Fermi level were derived for another GIC, LiC_6. The highest T_c achieved for a GIC was 5 K.[6] A parallel development was that of SC in Bechgard salts, the organic charge-transfer systems. Within this family of organic materials exhibiting carbon π-band conductivity, T_c has been raised to 12.5 K.[7] It should be noted that the majority of these compounds are unstable at normal conditions and high-pressure experiments are most common. This part of GIC studies was reviewed in Ref. 5.

Later research shifted to the area of carbides and nitrides of transition metals where metallicity and conductivity are mostly due to transition-metal atoms. Only in 1991 was it shown that alkali-doped C_{60} exhibits SC with maximum T_c of 33 K.[8] It was the first representative of a three-dimensional (3D) carbon-based metal with a modified (compared to graphite) coupling of lattice vibrations to the conduction electrons due to the curvature of the molecule but still with π-band derived states at the Fermi level.

We have calculated the electronic structure of MgB_2 and some related compounds using the Stuttgart linear muffin-tin orbital tight-binding in atomic sphere approximation (ASA) code and full-potential LMTO (FLMTO) method.[9] A local exchange-correlation potential was used in both cases (the addition of gradient corrections did not change the results). It appears that a general analysis of energy bands may be safely done in ASA, while a reliable treatment of charge densities and anisotropy of transport properties of these compounds requires more accurate FLMTO calculations.

In order to examine the relation between the band structure of MgB_2 and that of graphite we studied the following hypothetical sequence of intermediate materials: carbon in the "primitive graphite" (PG) lattice with no displacement between layers as in MgB_2 and in GIC's, using graphite lattice parameters; boron in the PG lattice with a as in MgB_2 and c/a as in graphite; boron in the PG lattice with a and c/a as in MgB_2; LiB_2 in the same structure; MgB_2 itself. The results of some of these calculations are shown in Fig. 1. The band structure of PG carbon shown in Fig. 1(a) is very similar to that of graphite (see, e.g., Ref. 10 and references therein) with the appropriate zone folding for a smaller unit cell. (This is quite natural because of the weak interlayer interaction.) Boron in the same lattice but scaled to match the MgB_2 in-plane lattice parameter (not shown) has nearly identical bands with the energies scaled by the inverse square of the lattice parameter, in agreement with common tight-binding considerations.[11] Figure 1(b) shows the natural enhancement of the out-of-plane dispersion of the π bands when the interlayer distance is reduced. Figures 1(c) and 1(d) demonstrate that "intercalation" of boron by Li or Mg produces a significant distortion of the band structure, so that the role of the intercalant is not simply one of donating electrons to boron's bands [which would return the band structure to that of PG carbon shown in Fig. 1(a)]. The main change upon intercalation is the downward shift of the π bands compared to σ bands. For Li this shift of ~ 1.5 eV is almost uniform throughout the Brillouin zone. Replacement of Li by Mg shifts the π bands further, but this shift is strongly asymmetric increasing from ~ 0.6 eV at the Γ point to ~ 2.6 eV at the A point. In addition, the out-of-plane dispersion of the σ bands is also significantly enhanced. In LiB_2 the filling of the bonding p_{xy} bands is nearly the same as in PG boron,

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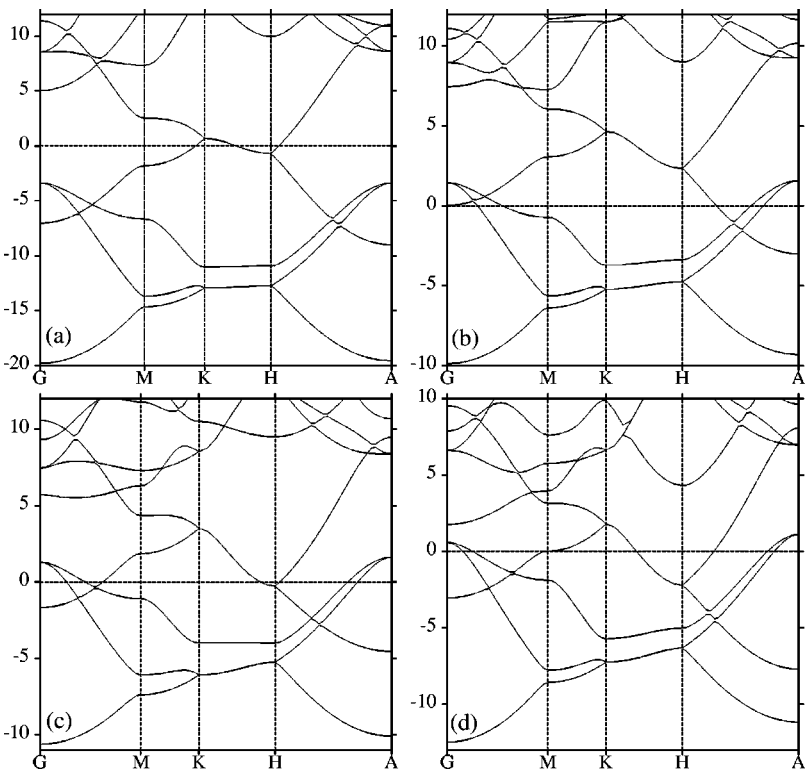

FIG. 1. Band structures of (a) primitive (*AA* stacking) graphite (PG), $a=2.456$ Å, $c/a=1.363$; (b) PG boron, $a=3.085$ Å, $c/a=1.142$ (as in MgB_2); (c) LiB_2 in MgB_2 structure, same a and c/a; (d) MgB_2, same a and c/a. Energy is in eV relative to E_F. The order of occupied bands in the Γ point is σ bonding with boron s character, π bonding with boron p_z character, and σ bonding with boron p_{xy} character (double degenerate).

while in MgB_2 the Fermi level shifts closer to the top of these bands.

The Fermi surface (FS) for MgB_2 obtained in the FLMTO method is practically identical to Fig. 3 of Ref. 2. The incompletely filled bonding σ bands with predominantly boron p_{xy} character form two hole-type cylinders around the Γ-A line, while the π bands form two planar honeycomb tubular networks: one electron-type network centered at $k_z=0$ and another similar, but more compact, hole-type network centered at $k_z=\pi/c$. The lowering of the π band in MgB_2 compared to the PG boron is connected with the charge transfer from magnesium to the interstitial region. The increased charge density in the interstitials also enhances the overlap of the boron p_z orbitals and hence the k_z dispersion.

The nature of bonding in MgB_2 may be understood from the charge density (CD) plots shown in Fig. 2. As seen in Fig. 2(a), bonding in the boron layer is typically covalent. The CD of the boron atom is strongly aspherical, and the directional bonds with high CD are clearly seen (see also Ref. 12). It is worth noting that the CD distribution in the boron layer is very similar to that in the carbon layer of graphite (see, e.g., Ref. 10). This directional in-plane bonding is also obvious from Fig. 2(b) showing the CD in a cross section containing both Mg and B atoms. However, Fig. 2(b) also shows that a large amount of valence charge does not participate in any covalent bonding, but rather is distributed more or less homogeneously over the whole crystal. Further, Fig. 2(c) shows the difference of the CD of MgB_2 and that of hypothetical NaB_2 in exactly the same lattice. Not only does it show that one extra valence electron is not absorbed by boron atoms but is rather delocalized in the interstitials; it also shows that some charge moves outward from boron atoms and covalent in-plane B-B bonds. Figure 2(d) shows the CD difference between the isoelectronic compounds MgB_2 and PG carbon (C_2). In MgB_2 the electrons see approximately the same external potential as in C_2, except that one proton is pulled from each C nucleus and put at the Mg site. It is evident that the change $C_2 \rightarrow MgB_2$ weakens the two-center σ bonds (the charge between the atoms is depleted) and redistributes it into a delocalized, metallic density.

Thus, the structure of MgB_2 is held together by strongly *covalent* bonding in boron sheets and by delocalized, *metallic*-type bonding between these sheets. A peculiar feature of this compound is that electrons participating in both of these bond types provide comparative contributions to the density of states (DOS) at the Fermi level (see below). This distinguishes MgB_2 from closely related GIC's where covalent bonds in the carbon sheets are always completely filled, while the nearly cylindrical parts of the FS commonly found in those compounds are formed by carbon-derived π bands that are also responsible for conductivity in pristine graphite.[5]

Because of the coexistence of two different types of chemical bonds, it is desirable to find the contributions to the total DOS and transport properties from separate pieces of the FS originating from two-dimensional (2D) covalent and 3D metallic-type bonding. Such decomposition is shown in Fig. 3 for the total DOS and for the in-plane (xx) and out-of-plane (zz) components of the tensor $\sigma_{\alpha\beta}=\int v_\alpha v_\beta \delta[\varepsilon(\mathbf{k})-E_F]d\mathbf{k}$, with v_α being a component of the electronic velocity. One can see that the 3D (metallic-type bonding) and cylindrical (covalent bonding) parts of the FS contribute, respectively, about 55% and 45% to $N(0)$. $N(\varepsilon)$ for the hole-type zones rapidly decreases with increasing ε and already at $\varepsilon \approx 0.8$ eV above E_F the total DOS is almost

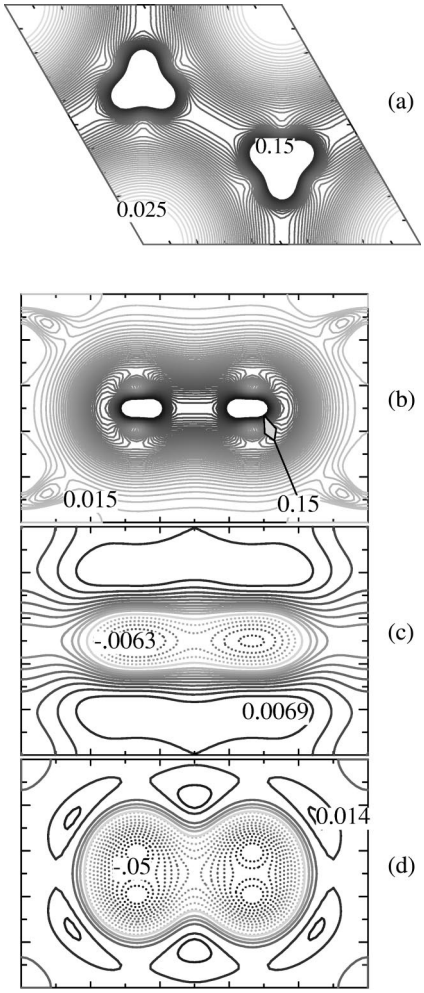

FIG. 2. Pseudocharge density contours obtained in FLMTO. The unit cell is everywhere that of MgB_2. The darkness of lines increases with density. (a) MgB_2 in the (0002) plane passing through B nuclei; (b) MgB_2 in the (1000) plane passing through Mg nuclei at each corner of the figure. B nuclei occupy positions (1/3,1/2) and (2/3,1/2) in the plane of the figure. The integrated charge of the unit cell is 8. (c) The (1000) plane, difference in smoothed density, MgB_2 minus NaB_2. The integrated charge of the unit cell is 1. (d) The (1000) plane, difference in smoothed density, MgB_2 minus PG carbon. The integrated charge of the unit cell is 0. In (a) and (b) the regions with high charge densities close to the nuclei are not plotted. In (c) and (d), dotted lines show negative values.

completely determined by the 3D electron-type band. The latter contribution is almost constant and probably is not related to the change of SC properties under pressure or with doping. The corresponding contribution to σ exceeds all other contributions (more than 50% for σ_{zz} and σ_{xx}) and is virtually isotropic. Holes in the in-plane B-B covalent bands (two cylinders at the FS) as expected have clearly anisotropic behavior contributing about 30% to σ_{xx} and virtually nothing to σ_{zz}. The 3D hole-type part of the FS is also notably anisotropic with predominantly z-axis conductivity. The total σ has a rather small anisotropy at E_F with $\sigma_{xx}/\sigma_{zz} \simeq 1.22$. The average projections of the Fermi velocities $\overline{v_\alpha} = \langle v_\alpha^2 \rangle^{1/2}$ are $\overline{v_x} = 5.36 \times 10^7$ cm/s, $\overline{v_z} = 4.85 \times 10^7$ cm/s. The average

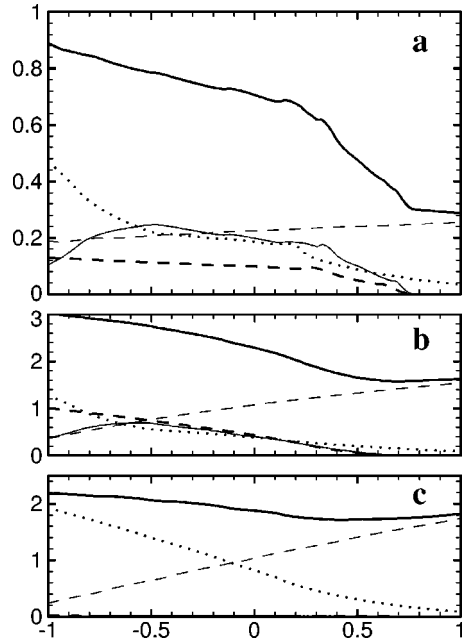

FIG. 3. Rigid band results for MgB_2: (a) total DOS in eV^{-1}/cell; (b) σ_{xx} and (c) σ_{zz} in Ry a_0^2 (for a definition of $\sigma_{\alpha\beta}$ see text), with contributions from different parts of the FS. Thick solid lines: total; thin dashed lines: 3D electronic part; dotted lines: 3D hole part; thick dashed lines: internal cylinder; thin solid lines: external cylinder. Energy is in eV relative to E_F.

Fermi velocities $\overline{v_\nu} = \langle v^2 \rangle_\nu^{1/2}$ for each Fermi-surface sheet ν are as follows: internal cylinder, 8.85×10^7 cm/s; external cylinder, 6.02×10^7 cm/s; 3D electronic sheet, 1.12×10^8 cm/s; 3D hole sheet, 8.74×10^7 cm/s.

The main challenge is to suggest another possible SC with a higher T_c. We studied several similar systems that, as we believe, may be interesting for experimental studies. Several isoelectronic compounds demonstrate very different behavior. Hypothetical BeB_2 and ZnB_2 in the MgB_2 structure are very similar to MgB_2 in terms of the electronic properties. Our ASA calculations of these compounds with lattice parameters of MgB_2 produced very similar band structures with nearly identical FS. Presumably a smaller radius of the Be ion and a larger one of the Zn ion will generate some difference but we expect that these compounds (if existing) would have properties similar to MgB_2. Another isoelectronic system is lithium borocarbide, LiBC,[13] which, according to our ASA results, is a perfect insulator, so that any substitution of C by B will lead to metallic behavior. (In general, the obtained band structure of this system is very similar to that of BN.[14]) Experimentally very small conductivity was observed in LiBC.[13]

The addition of one electron to MgB_2 corresponds to AlB_2. This compound also has metallic conductivity but its FS does not have any cylindrical parts as in MgB_2. Experimentally no T_c has been observed[15] which makes electron doping an unlikely mechanism to increase T_c. Under such circumstances it would be most logical to try hole doping by replacing Mg by Na or Li. Unfortunately such compounds

are unstable. We are familiar only with one experimental report that NaC_2 (Ref. 16) is a weak SC under pressure and is very unstable. However, it may be possible to form an alloy $(Mg,Na)B_2$ with modest amounts of Na. It is evident from Fig. 3 that the hole-type parts of the FS change dramatically with electron filling. More relevant discussions can be found in Ref. 17.

In summary, MgB_2 represents the first relatively high-T_c superconducting compound of boron and has very peculiar bonding characteristics compared to GIC. We showed that the electronic structure of MgB_2 has both similarity to and notable differences with the GIC's. These features provide a basis both for further studies of normal andSC states of MgB_2 and for engineering new SC compounds.

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